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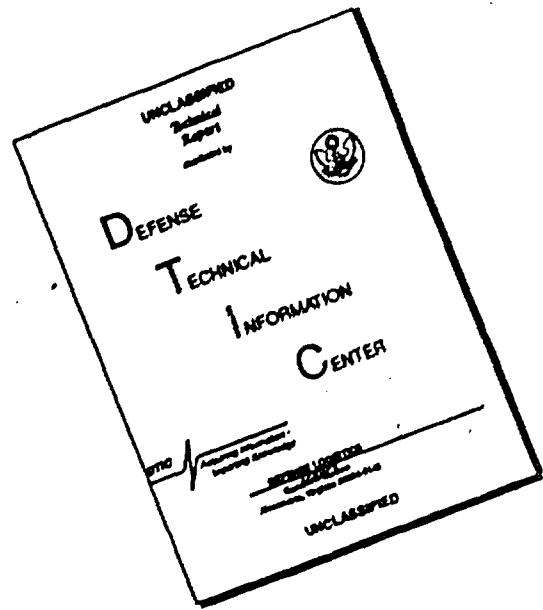
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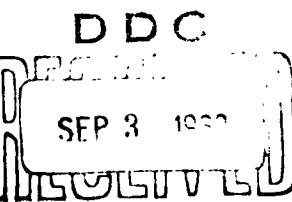
THERMOPHYSICAL PROPERTIES OF SOME CANDIDATE  
SUPERORBITAL HEAT SHIELD AND INSULATION MATERIALS

Prepared By

Materials Applications Division  
AF Materials Laboratory  
Deputy Cmdr/Research & Engineering

6 June 1963

Task 738103



Aeronautical Systems Division  
Air Force Systems Command  
United States Air Force  
Wright-Patterson Air Force Base, Ohio

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Technical Memorandum  
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THERMOPHYSICAL PROPERTIES OF SOME CANDIDATE  
SUPERORBITAL HEAT SHIELD AND INSULATION MATERIALS

I. PURPOSE:

The purpose of this memorandum is to present a concise summary of the most useful thermophysical properties of some candidate heat shield materials for the thermal protection of superorbital lift reentry vehicles.

II. FACTUAL DATA

1. The following materials properties reports and compendia were searched for pertinent data:

- (a) WADC TR58-476
- (b) ASD TR62-215
- (c) TPRC Data Book Vol. 1, 2, & 3
- (d) DMIC Memo 141
- (e) WADC TR57-476
- (f) ASD TR62-765
- (g) DMIC Memo 177

III. CONCLUSIONS

1. The data sheets (Appendix I) constitute Information Processing Section's first compilation in this specific area, and it is intended to be the most complete summary of the data in published unclassified reports and data compendia.

2. In evaluating the reliability of the data, we suggest that the source reference be noted and that they have the following order, the most reliable first:

- (a) TPRC Data Book
- (b) DMIC Memo 141 & 177
- (c) ASD & WADC Technical Reports

3. The emissivity data, while the best available, is probably the least reliable of the data presented.

IV. RECOMMENDATIONS:

It is recommended that this initial review be continued and updated as may be warranted by the availability of new and/or more refined data.

COORDINATION:

  
Edward Dugger, ASRCE-31

[REDACTED]

PREPARED BY:

  
John H. Charlesworth, ASRCE-31

PUBLICATION REVIEW

This report has been reviewed and is approved.



D. A. SHINN  
Chief, Materials Information Branch  
Materials Applications Division  
AF Materials Laboratory

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THERMOPHYSICAL PROPERTIES - SUPERHEATED WATER & INSULATION MATERIALS													
Ref.	Material	Density g/cm <sup>3</sup>	Condition	E. F.	Thermal Conductivity Watts/cm <sup>2</sup> K	E Watts/cm <sup>2</sup> K	G Temp	Electrical Resistivity Ω cm	Resistivity Δ Temp	Specific Heat J/g·°K	Δ Temp	Linear Thermal Expansion E 10 <sup>-6</sup> /°K	
TRDC TR54-476 Vol. I	Graphite gr GRK	1.09			35.0 16.0	350000 500000	100000 500000	0.8870-6650 0.79	800000 500000	0.46 0.76	2000°K 7000°K		
—	Carbon (heat preheated per reference)	1.10											
—	Graphite Acheson Type 7007	101.7	Extruded multi-crystalline		46.0 20.0	1500000 5000000	≤ 40000 ≤ 40000			0.5 0.75	3000°K 7000°K	1.06 1.16 2.20	
—	Graphite Acheson Type 200		Extruded multi-crystalline		45 11	1500°K 5000°K	≤ 40000 ≤ 40000	0.79 0.70	2000°K 5000°K		0.80 0.97 1.00	10000°K 10000°K 10000°K	
—	Graphite Acheson Type 8700D	104	Extruded multi-crystalline		70 2	1000000 5000000	≤ 40000 ≤ 40000	0.75 0.75	1000°K		0.98 2.10	1000°K 1000°K 7000°K	
ASD TR62-215	Pyrolytic graphite	114.5-130 130.5	6000°K	1.9 (Max) 0.4 (Avg)	200 (Max) 50 (Avg) W/m <sup>2</sup> K	200000 500000	≤ 40000 ≤ 40000	0.66 0.66	1000°K 2000°K	0.083 0.083	5000°K 2000°K	2.7 (Max) 2.650	
TRDC TR-111-3	Graphite GRK	99.5			0.491 Watts/ 0.459 cm <sup>2</sup> K	1000°K 1000°K							
—	Graphite Type 5274	100.6			0.491 0.467	1000°K 1000°K							
—	Graphite Acheson				0.333	1000°K	≤ 40000						
—	Carbon (Pure filament)				0.340 0.300	1000°K 1000°K	≤ 40000 ≤ 40000						
TRDC TR-111	Graphite	0.110 g/cm <sup>3</sup>	1.1. T.	11.1°K	50	1000°K	≤ 40000	0.12 (Total) 0.12 (Parallel) 0.12 (Transverse)	1000°K				
—	Tantalum	6.600 g/cm <sup>3</sup>	1.1. T.	6.600	0.1140 0.1000	50	1000°K 1000°K	0.79 °C Heat 0.71 (Polished)	1000°K 2000°K	1.067 3.004	0.0 0.4	60°K 5000°K	
—	Cerium	4.240 g/cm <sup>3</sup>	1.1. T.	4.240	0.1000	50	1000°K	0.097 0.097 0.097 (Estimated)	1000°K				
—	Boron Nitride	2.100 g/cm <sup>3</sup>	1.1. T.	2.100	0.1000	1.2	1000°K	0.097 0.097 0.097 (Estimated)	1000°K	0.135	2000°K	0.0 1.0 60°K	
—	Tungsten	1.907 g/cm <sup>3</sup>	1.1. T.	1.910	1.051*	40	1000°K	0.097 0.097 0.097 (Estimated)	1000°K 1000°K	0.095(1) 0.095(1)	2000°K	0.0 1.0 60°K	
—	Rhenium	1.220 g/cm <sup>3</sup>	1.1. T.	1.220	21	1000°K							
TRDC TR-111-67	Mesolite I Mesolite II Stellite I Si-3177H Si-316B				15.1 15.2 20.7 19.2 21.8	1000°K 1000°K 1000°K 1000°K 1000°K				0.155 0.149 0.129 0.119 0.109	2000°K		
TRDC TR54-476 Vol. II	Alumina Al2O <sub>3</sub>	3.97 g/cm <sup>3</sup>	1140°K	0.00000	0.5	1000°K 1000°K	≤ 40000 ≤ 40000	0.01 (Normal) 0.02 (Normal)	1000°K 1000°K	0.26 0.33	1000°K 1000°K	0.0 1.0 60°K	
—	Silicon Nitride Si3N <sub>4</sub>	3.27 g/cm <sup>3</sup>	1140°K	0.00000	0.5	1000°K 1000°K	≤ 40000 ≤ 40000	0.01 (Normal) 0.02 (Normal)	1000°K 1000°K	0.097(1) 0.107(1)	1.0 1.95	60°K 6000°K	
—	Barium Oxide	2.97 g/cm <sup>3</sup>	1140°K	0.00000	0.1	1000°K 1000°K	≤ 40000 ≤ 40000	0.01 (Normal) 0.02 (Normal)	2000°K	0.26	2000°K	0.0 1.0 60°K	
—	Barium Oxide CaO <sub>2</sub>	4.61 g/cm <sup>3</sup>	1140°K	0.00000	0.1	1000°K 1000°K	≤ 40000 ≤ 40000	0.13(1) 0.14(1)	2000°K 2000°K	0.067(1) 0.068(1)	1.0 0.42	1000°K 1000°K	
—	Hypochlorite Oxide BaO <sub>2</sub>	3.69 g/cm <sup>3</sup>	1140°K	0.00000	0.1	1000°K 1000°K	≤ 40000 ≤ 40000	0.01 (Normal) 0.02 (Normal)	2000°K	0.26	2000°K	0.0 1.0 60°K	
—	Borosilicate Oxide BaO <sub>3</sub>	4.61 g/cm <sup>3</sup>	1140°K	0.00000	0.1	1000°K 1000°K	≤ 40000 ≤ 40000	0.01 (Normal) 0.02 (Normal)	2000°K	0.26	2000°K	0.0 1.0 60°K	
—	Lead Borate Oxide BaO <sub>3</sub>	4.77 g/cm <sup>3</sup>	1140°K	0.00000	0.1	1000°K 1000°K	≤ 40000 ≤ 40000	0.01 (Normal) 0.02 (Normal)	2000°K	0.077 0.075	1000°K 2000°K	0.0 1.0 60°K	
—	Lanthanum Borate La <sub>2</sub> O <sub>3</sub>	4.06 g/cm <sup>3</sup>	1140°K	0.00000	0.1	1000°K 1000°K	≤ 40000 ≤ 40000	0.0985 0.100	1000°K 2000°K	0.0865 0.072	1000°K 1000°K	0.0 1.0 60°K	
—	Silicon Carbide SiC <sub>2</sub>	3.600 g/cm <sup>3</sup>	1140°K	0.00000	0.1	1000°K 1000°K	≤ 40000 ≤ 40000	0.09	2000°K				
—	Magnesium Oxide MgO	3.99 g/cm <sup>3</sup>	1140°K	0.00000	0.1	1000°K 1000°K	≤ 40000 ≤ 40000	0.05 (Normal) 0.11 (Normal)	1000°K 1000°K	0.36(1) 0.36(1)	5000°K 5000°K	0.0 0.35	5000°K 5000°K
ASD TR62-25	Polyethylene Ecolite	0.90 g/cm <sup>3</sup>	5300°K		29.0 17.0	1100°K 2000°K				0.105 0.13	4000°K 2000°K	0.0 1.30	5000°K 5000°K

Figures indicated by asterisks from TRDC

Figures indicated by (1) from TR54-476

Symbols Δ measured parallel to direction of processing (extrusion, stretching, etc.)

Symbols || measured parallel to direction of processing (extrusion, stretching, etc.)

THERMOPHYSICAL PROPERTIES - SUPERCONDUCTING & INSULATION MATERIALS														
Ref.	Material	Density g/cm <sup>3</sup>	Condition	M. P. °C	Thermal Conductivity Watts/cm °C	$\lambda$ W/m K	Temp. °C	Electrical Resistivity	Resistivity n	Temp. °K	Specific Heat J/Kg °K	Temp. °K	Linear Thermal Expansion E - °C/mm	
REF. TR54-476 Vol. III	Barium Oxide BaO <sub>2</sub>	6.04 g/cm <sup>3</sup>	97000		0.95 0.90	10000 20000		$n_{\text{inf}}(1)$ $n_{\text{inf}}(2)$	$15000(1)$ $10000(1)$	$0.09(1)$ $0.15(1)$	$4000(1)$ $4000(1)$	0.0	5200	
* *	Thorium Oxide ThO <sub>2</sub>	6.04 g/cm <sup>3</sup>	65700		0.0099	8.7 2.0	1173.26 9000 20000		0.59 Total 0.12 Normal	12000 20000	0.07(1) 0.08(1)	5000(1) 5000(1)	1.48 1.40	
* *	Uranium Dioxide UO <sub>2</sub>	6.04 g/cm <sup>3</sup>	56700		0.0149	9.8 0.6	17000 1900.18 30000			0.070	10000 25000	0.0 1.70	5200 25000	
* *	Zirconium Nitride ZrN <sub>2</sub>	3.60 g/cm <sup>3</sup>	53700		0.0209	1.0 1.24	10000 1600.26 30000			0.136 0.144	10000 30000	$6.104 \times 10^{-12}$ $10^{-12}$	25000 <sup>(1)</sup>	
* *	Chromium Carbide Cr <sub>3</sub> C <sub>2</sub>	4.27 g/cm <sup>3</sup>	38000								0.169 0.210	10000 20000		
Vol. IV	Niobium Carbide NbC	7.00 g/cm <sup>3</sup>	75000			9.2(1) 17.9(1)	10000(1) 10000(1)		0.99(1) 0.85(1)	15000(1) 10000(1)				
* *	Holmium Carbide HoC	5.75 g/cm <sup>3</sup>	53500						0.67(1) 0.70(1)	10000(1) 10000(1)	0.085(1) 0.125(1)	4000(1) 30000(1)	0.0 0.76 0.16	5200 22500 <sup>(1)</sup> metal 22500 <sup>(1)</sup> metal
* *	Tantalum Carbide TaC	9.00 g/cm <sup>3</sup>	71000						0.16(1) 0.25(1)	10000(1) 10000(1)			0.0	5200
* *	Titanium Carbide TiC	3.97 g/cm <sup>3</sup>	61000		0.0619	10.0 2.9	10000 1900.18 30000		$n_{\text{inf}}(1)$ $n_{\text{inf}}(2)$	10000(1) 4000(1)	0.146 0.22	10000 30000	0.0 1.70	5200 30000
* *	Tungsten Carbide WC	19.56 g/cm <sup>3</sup>	56000			25.0(1) 31.7(1)	10000(1) 10000(1)		0.4(1) 0.4(1)	10000(1) 10000(1)	0.05(1) 0.08(1)	5000(1) 10000(1)	0.0 0.70	5200 30000
* *	Uranium Carbide Ug <sub>2</sub>	7.93 g/cm <sup>3</sup>	47000			10.0	6000							
A-D-TM4-765	Vanadium Carbide	5.162 g/cm <sup>3</sup>				21.6 21.3	10000 10000		0.69 0.75	10000(1) 10000(1)	0.180 0.35	4000(1) 30000(1)	$4.10 \times 10^{-12}$ $0.35000$	0.35000
REF. TR54-476 Vol. IV	Silicon Carbide SiC <sub>2</sub>	3.69 g/cm <sup>3</sup>	60000			7.5 16.0(1)	5000 30000(1)		0.15(1) 0.15(1)	10000(1) 30000(1)			0.0	5200
REF. TR54-476 Vol. IV	Silicon Carbide SiC	3.60 g/cm <sup>3</sup>	64000						0.45 - 1.0(2)	10000(2)			0.0	5200
* *	Vanadium Boride Vb <sub>2</sub>	7.00 g/cm <sup>3</sup>	65100			11.7(1) 23.0(1)	10000(1) 30000(1)		0.14(1) 0.17(1)	10000(1) 30000(1)	0.084(1) 0.180(1)	10000(1) 10000(1)	$4.5 \times 10^{-12}$ $0.40000$	0.40000
* *	Boron Nitride BN <sub>2</sub>	1.60 g/cm <sup>3</sup>	47000											
* *	Plutonium Boride PB <sub>2</sub>	1.60 g/cm <sup>3</sup>	59000											
* *	Titanium Boride TiB <sub>2</sub>	1.97 g/cm <sup>3</sup>	46000											
A-D-TM4-765	Tungsten Carbide WC	15.2 g/cm <sup>3</sup>				26.4 23.4	10000 10000		0.5	10000 10000	0.06 0.10	4000 30000	$4.5 \times 10^{-12}$ $0.40000$	0.40000
REF. TR54-476 Vol. IV	Vanadium Boride Vb <sub>2</sub>	3.60 g/cm <sup>3</sup>	47000											
* *	Titanium Nitride TiN	3.96(1) g/cm <sup>3</sup>	53500(1)			11.0 3.0	10000 30000 1950 MP 30000	$\sigma = 6.6 \times 10^{-5} \text{ ohm} \cdot \text{cm}$	0.46(1) 0.50(1)	10000(1) 4000(1)	0.145 0.22	4000 30000		
* *	Boron Nitride BN	2.99 g/cm <sup>3</sup>	50000			2.95	5000							
* *	Silicon Nitride Si <sub>3</sub> N <sub>4</sub>	3.68 g/cm <sup>3</sup>	51500		0.0999	6.7 5.3	10000 1500.18 30000		0.09 Total Normal	10000 30000	0.098 0.135	4000 30000	0.0 1.16	5200 11000
A-D-TM4-765	Titanium Nitride	3.54 g/cm <sup>3</sup>							0.76	10000 10000	0.05 0.09	4000 30000	$2.1 \times 10^{-12}$ $0.40000$	0.40000
A-D-TM4-215	Boron Carbide B <sub>3</sub> N <sub>2</sub>	3.6109 g/cm <sup>3</sup>				0.65	10000				0.75	20000		
* *	Boron Carbide B <sub>4</sub> C	1.94 g/cm <sup>3</sup>	44400	14	PCB 30000						0.295	4000	0.0 1.9	5200 30000
* *	Silicon Carbide SiC	3.01 g/cm <sup>3</sup>	47100	8	30000						0.09	4000	0.0 1.2	5200 30000
* *	Boron Nitride BN	1.97 g/cm <sup>3</sup>	50000			16 7	50000 10 30000 1.5		0.15 Total Normal	10000 30000	0.97(1) 0.94(1)	4000(1) 30000(1)	0.0 1.2	5200 30000
* *	Al <sub>2</sub> O <sub>3</sub> -Cr <sub>2</sub> O <sub>3</sub> System	1.98 to 2.90 g/cm <sup>3</sup>	> 57000			Modulus 2000 to 3.5	21000						0	5200 30000
* *	Yttrium-Al <sub>2</sub> O <sub>3</sub>	20.0 g/cm <sup>3</sup>	56000			3.0 1.70	5000 30000						0	10000
* *	Er <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub>	3.64 g/cm <sup>3</sup>	43500			2.9 1.9	10000 30000				0.16 0.18	4000 30000	0.0 0.75	5200 30000

Figures indicated by asterisk from TPC.  
 Figures indicated by (1) from TR54-765.  
 Figures indicated by (2) from BNL Report 177.  
 Figures indicated by (3) from BNL TR54-825.